

RZ/G3E

AWO Example Program Startup Guide

Introduction

This material shows how to set up and invoke AWO Example Program for RZ/G3E.

Target Device

RZ/G3E

Contents

1. Specifications	2
1.1 Deliverables.....	2
2. Proven Environment	2
3. AWO Example Program Setup for RZ/G3E	2
3.1 Setup of Cortex-A55 software related stuff	2
3.2 Deployment of CA55 Build Artifacts	3
3.3 Setup of CM33 software related stuff.....	5
3.4 Deployment and debugging of AWO Example program	7
4. AWO Example Program Invocation	10
5. Function Reference of AWO Example Project	11
5.1.1 awo_thread_entry.....	11
5.1.2 awo_req_isr.....	11
5.1.3 transition_to_awo	12
5.1.4 transition_to_all_on	12
5.1.5 pmic_sleep_to_active.....	12
5.1.6 cluster_warm_reset_ca55	13
5.1.7 release_cluster_warm_reset_ca55	13
Revision History	14

1. Specifications

1.1 Deliverables

Table 1-1. Deliverables of RZ/G AWO Example Project

Deliverables	File name	Description
RZ/G3E Cortex®-M33 AWO example project	freertos_w_awo_rzg3e_evk_ep.zip	AWO example project for RZ/G3E.
RZ/G3E AWO Example Program Start-up Guide	r01an7882ej0100-rzg3e-awo-example-program-startup-guide.pdf	This material.

2. Proven Environment

Environments	Contents and versions
Integrated Development Environment	e2 studio 2025-07
JTAG Emulator	Segger J-Link 7.96j
Dependent Software	<ul style="list-style-type: none"> RZ/G3E Linux BSP v1.0.0 RZ/G Flexible Software Package (FSP) v3.1.0

3. AWO Example Program Setup for RZ/G3E

3.1 Setup of Cortex-A55 software related stuff

The steps are based on **RZ/G3E-EVKIT Linux Start-up Guide** (hereinafter referred to as **Linux Start-up Guide**) included in **RZ/G3E Linux BSP v1.0.0**.

- Follow the procedure stated from the beginning of **2.2 Building Images** to **(3) Add layers** of **Linux Start-up Guide**.
- Download Multi-OS Package (r01an5869ej0300-rzg-multi-os-pkg.zip) to a working directory and run the commands stated below:

```
cd ~/rzg_vlp_<pkg ver>
$ unzip <Multi-OS Dir>/r01an5869ej0300-rzg-multi-os-pkg.zip
$ tar zxvf r01an5869ej0300-rzg-multi-os-pkg/meta-rz-features_multi-os_v3.0.0.tar.gz
```

Here, <Multi-OS Dir> indicates the path to the directory where Multi-OS Package is placed.

- Uncomment the following lines in **meta-rz-features/meta-rz-multi-os/meta-rzg3e/conf/layer.conf**.

```
MACHINE_FEATURES_append = " RZG3E_CM33_BOOT"
#MACHINE_FEATURES_append = " CM33_FIRMWARE_LOAD"
#MACHINE_FEATURES_append = " CA55_CPU_CLOCKUP"
```

Be sure NOT to uncomment the above-mentioned 3rd and 4th line when CM33 cold boot support is enabled.

- Add the layer for Multi-OS Package.

```
$ cd build
$ bitbake-layers add-layer ../meta-rz-features/meta-rz-multi-os/meta-rzg3e
```

5. Start a build as described in **(5) Start a build of 2.2 Building Images** as shown below:

```
$ MACHINE=smarc-rzg3e bitbake core-image-<target>
```

For details on the allowable value of <target>, please refer to **Linux Start-up Guide**.

3.2 Deployment of CA55 Build Artifacts

- 1. Connect SER3_UART of RZG3E SMARC EVK with Host PC and established serial port connection.
- 2. Configure DIPSW of RZ/G3E SMARC EVK as follows, to specify CA55 cold boot and SCIF download mode.

BOOT

	1	2	3	4	5	6
ON						
OFF						

SW_MODE

	1	2	3	4
ON				
OFF				

3. Turn on RZ/G3E SMARC EVK. Then, the following message is shown on your terminal:



Figure 5-3. SCIF Download mode

4. Send **Flash_Writer_SCIF_RZG3E_EVK_LPDDR4X.mot** to RZ/G3E SMARC EVK via terminal software. If it's successfully transferred, the following message is shown on your terminal:

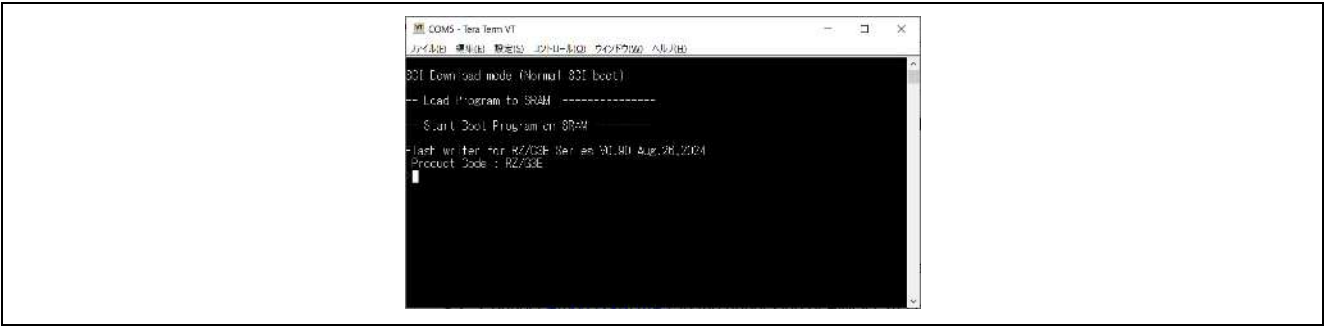


Figure 5-4. Flash Writer invocation

5. Program **bl2_bp_spi-smarc-rzg3e.srec** with Flash Writer as shown below:

```

xls2
===== Qspi writing of RZ/G2 Board Command =====
Load Program to Spiflash
Writes to any of SPI address.
Program size & Qspi Save Address
===== Please Input Program Top Address =====
    Please Input : H'8003600

===== Please Input Qspi Save Address ===
    Please Input : H'100000
please send ! ( '.' & CR stop load)
Erase SPI Flash memory...
Erase Completed
Write to SPI Flash memory.
===== Qspi Save Information =====
SpiFlashMemory Stat Address : H'00100000
SpiFlashMemory End Address  : H'00136D17
=====

```

6. Program **fip-smarc-rzg3e.srec** with Flash Writer as shown below:

```

xls2
===== Qspi writing of RZ/G2 Board Command =====
Load Program to Spiflash
Writes to any of SPI address.
Program size & Qspi Save Address
===== Please Input Program Top Address =====
    Please Input : H'00000

===== Please Input Qspi Save Address ===
    Please Input : H'160000
please send ! ( '.' & CR stop load)
Erase SPI Flash memory...
Erase Completed
Write to SPI Flash memory.
===== Qspi Save Information =====
SpiFlashMemory Stat Address : H'00280000
SpiFlashMemory End Address  : H'0033C2BE
=====

```

3.3 Setup of CM33 software related stuff

1. Extract **r01an5869ej0300-rzg-multi-os-pkg.zip** on your development PC.
2. Extract either of **freertos_w_awo_rzg3e_evk_ep.zip** included in **r01an5869ej0300-rzg-multi-os-pkg**.
3. Invoke e² studio 2025-07 and click **File > Import**.
4. Double-click **General** and select **Existing Projects into Workspace** as shown in Figure 3-1:

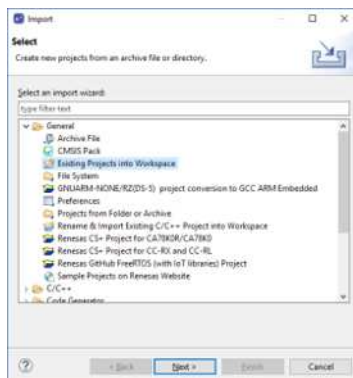


Figure 3-1. Import sample project (1)

5. Input the path to the directory of sample project you would like to import to **Select root directory**, press **Enter** key and click **Finish** button.

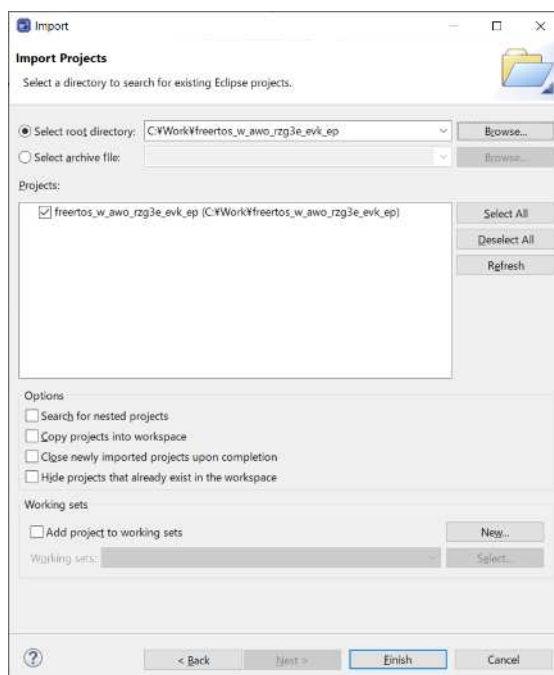


Figure 3-2. Import sample project (2)

6. Open **configurator.xml** in the project and choose **BSP** tab.
7. Configure **Launch CA55(core0)** as Enabled. Also, enabled **Clock up for CA55** if you would like to configure operational frequency of CA55 as 1.8GHz.
8. Click **Generate Project Content** to reflect the changes to your project.

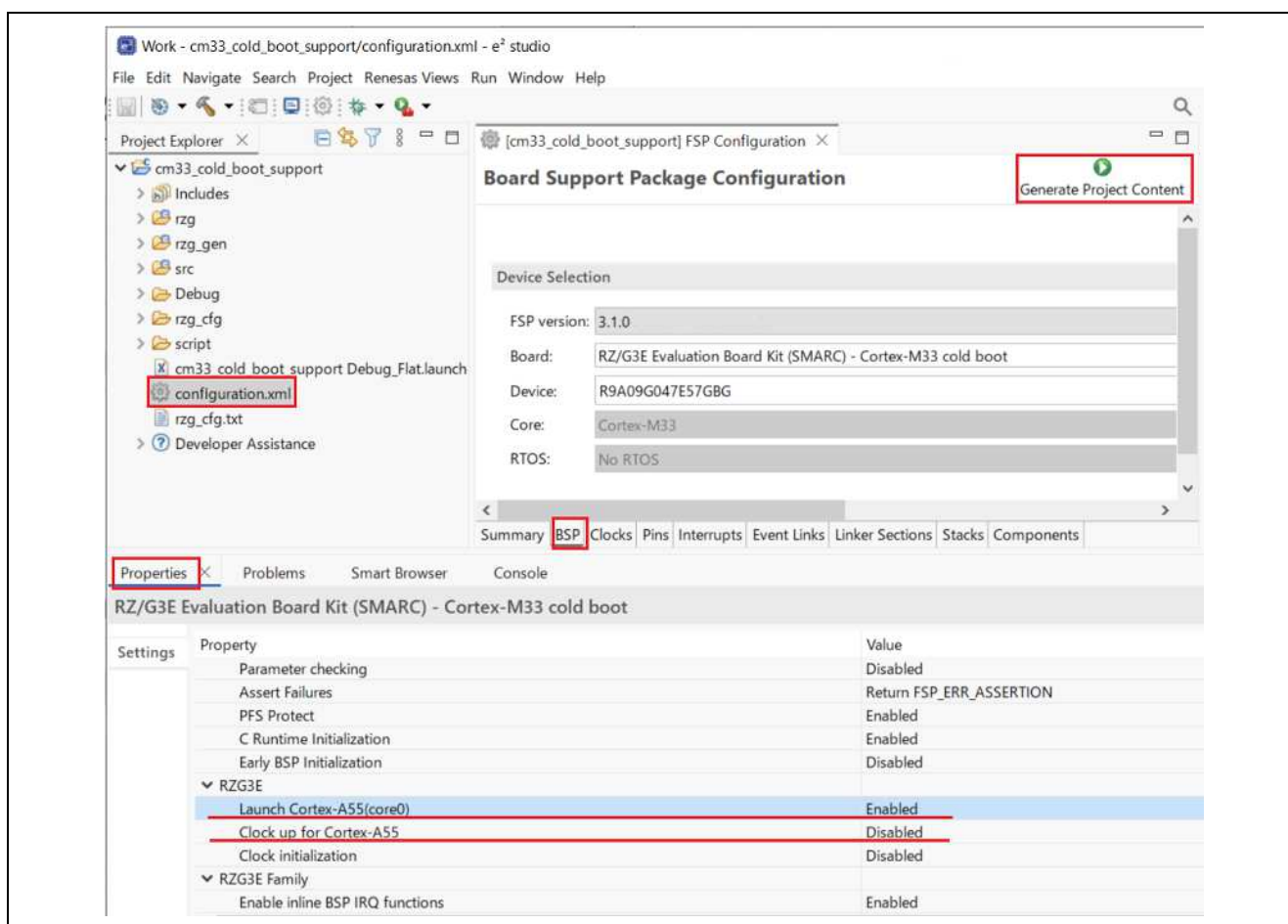


Figure 3-3. CM33 project setting for CM33 cold boot

9. Build the project from **Choose Project > Build Project**.
10. If building project is successfully completed, build artifacts as listed below should be generated in **Debug** or **Release** directory of the project you imported in accordance with the active Build Configuration.
 - freertos_w_awo_rzg3e_evk_ep.elf

3.4 Deployment and debugging of AWO Example program

1. Click **Run > Debug Configurations...**, expand **Renesas GDB Hardware Debugging** and choose **freertos_w_awo_rzg3e_evk_ep Debug_Flat**.

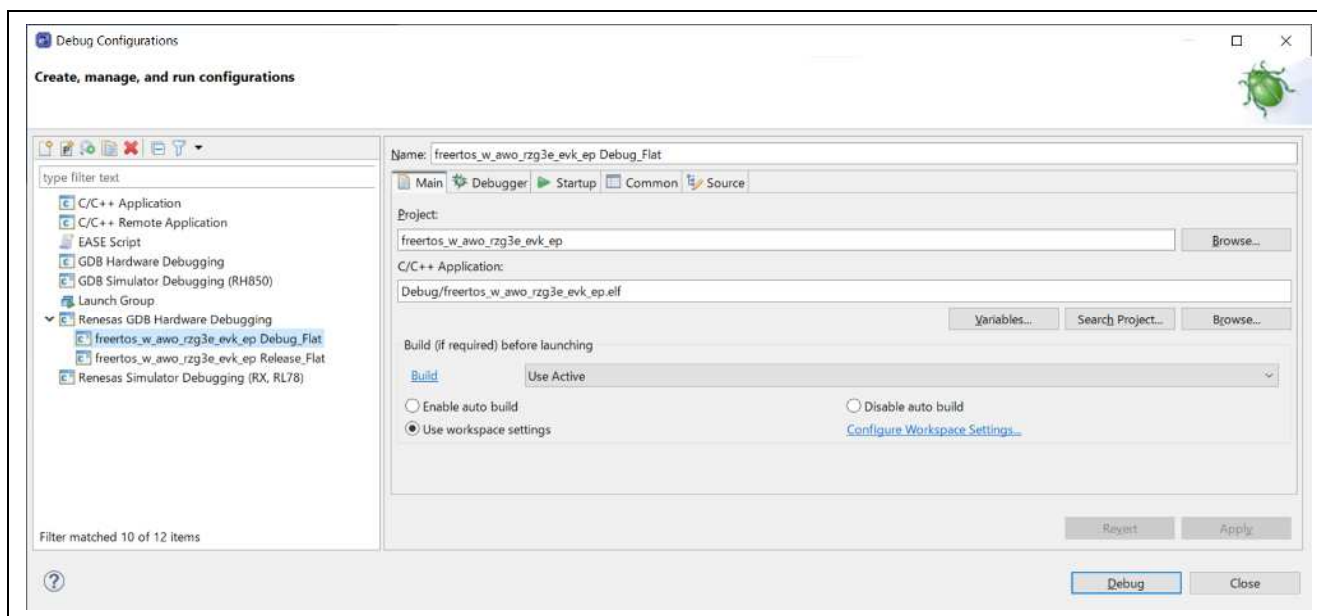


Figure 3-4. Debug Configuration Launch

(Optional)

2. Create a **CA55_SREC** folder directly under the project. Then copy the files used in **3.2 Deployment of CA55 Build Artifacts** into the folder.

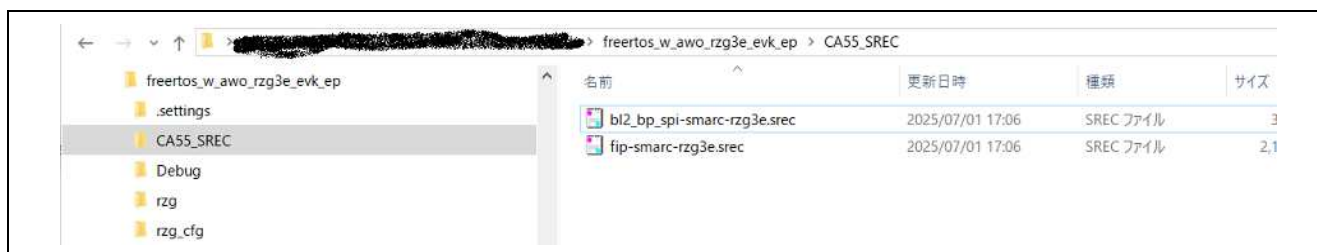


Figure 3-5. Copy of CA55 build artifacts

(Optional)

3. Check the following boxes in the debugger connection settings. Then the files copied in Step 2 will be written at the same time.

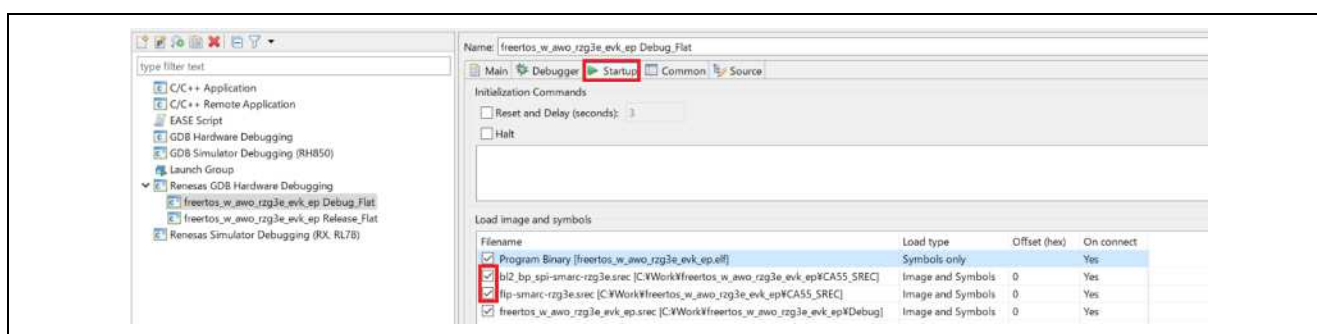


Figure 3-6. Specify the download of additional files

4. Click **Debug** button as shown below:

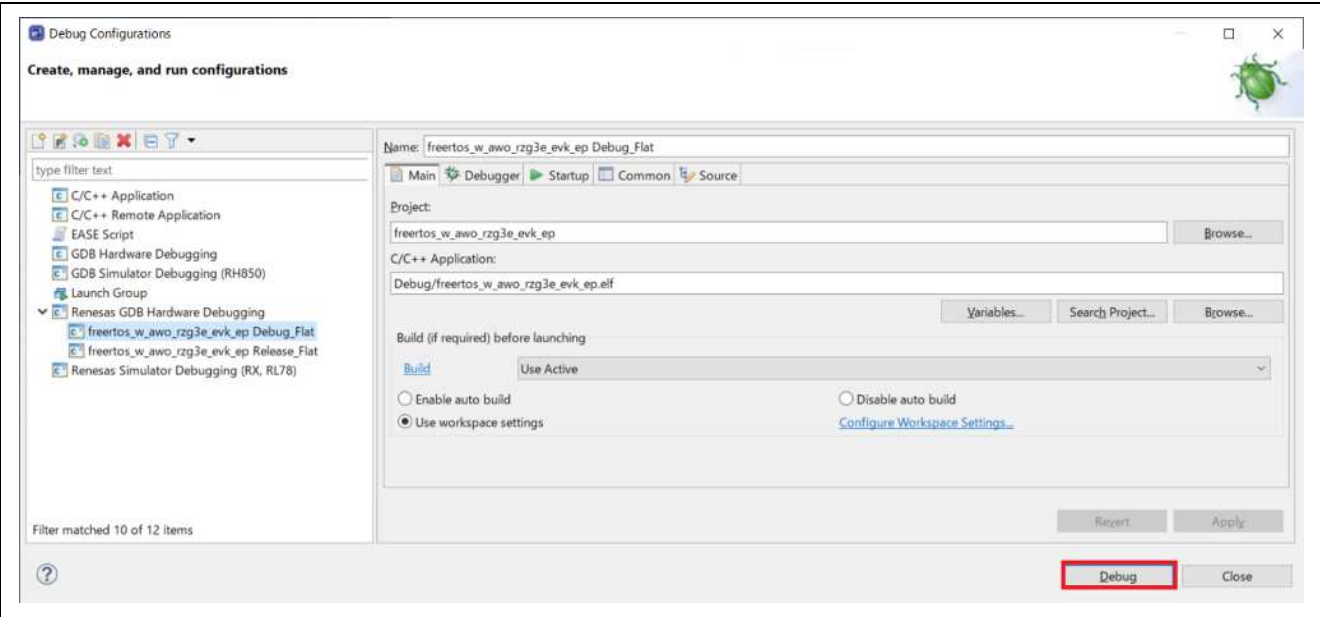


Figure 3-7. Debug Perspective Launch (1)

Note1: Configure DIPSW of RZ/G3E SMARC EVK as follows, to specify CM33 cold boot and SPI boot mode in advance.

BOOT

	1	2	3	4	5	6
ON						
OFF						

SW_MODE

	1	2	3	4
ON				
OFF				

If the following **Confirm Perspective Switch** window appears, press **Switch** to go ahead.

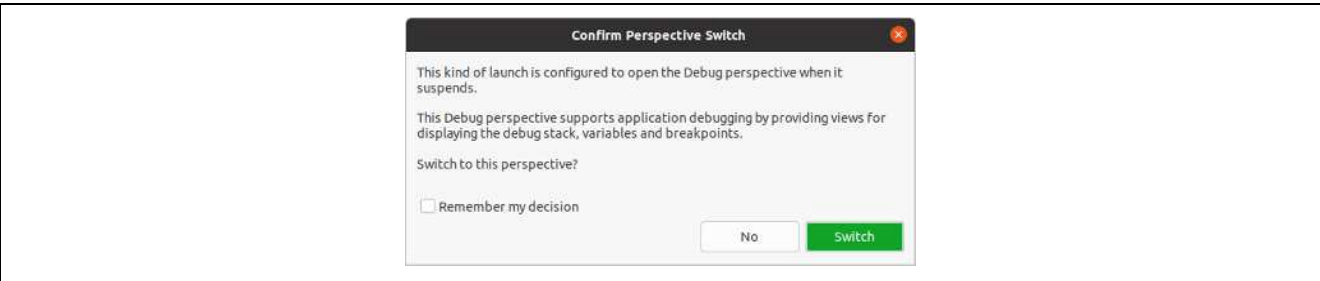


Figure 3-8. Debug Perspective Launch (3)

4. When **Debug Perspective** is opened, Program Counter (PC) should be located as shown in Figure 3-9. Then, continue the program to push the button shown in Figure 3-9.

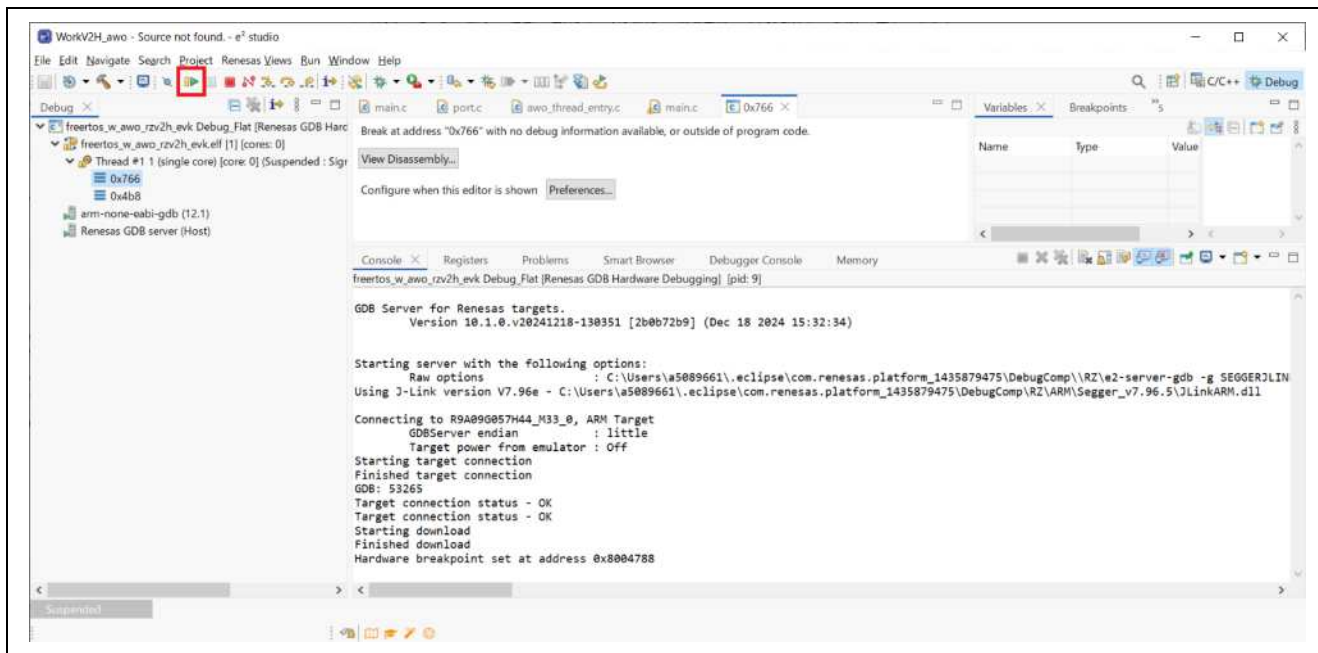


Figure 3-9. How to start to AWO Example Program (1)

5. PC should be stopped at the top of **main** function. Then, click the same button in the previous step to continue.

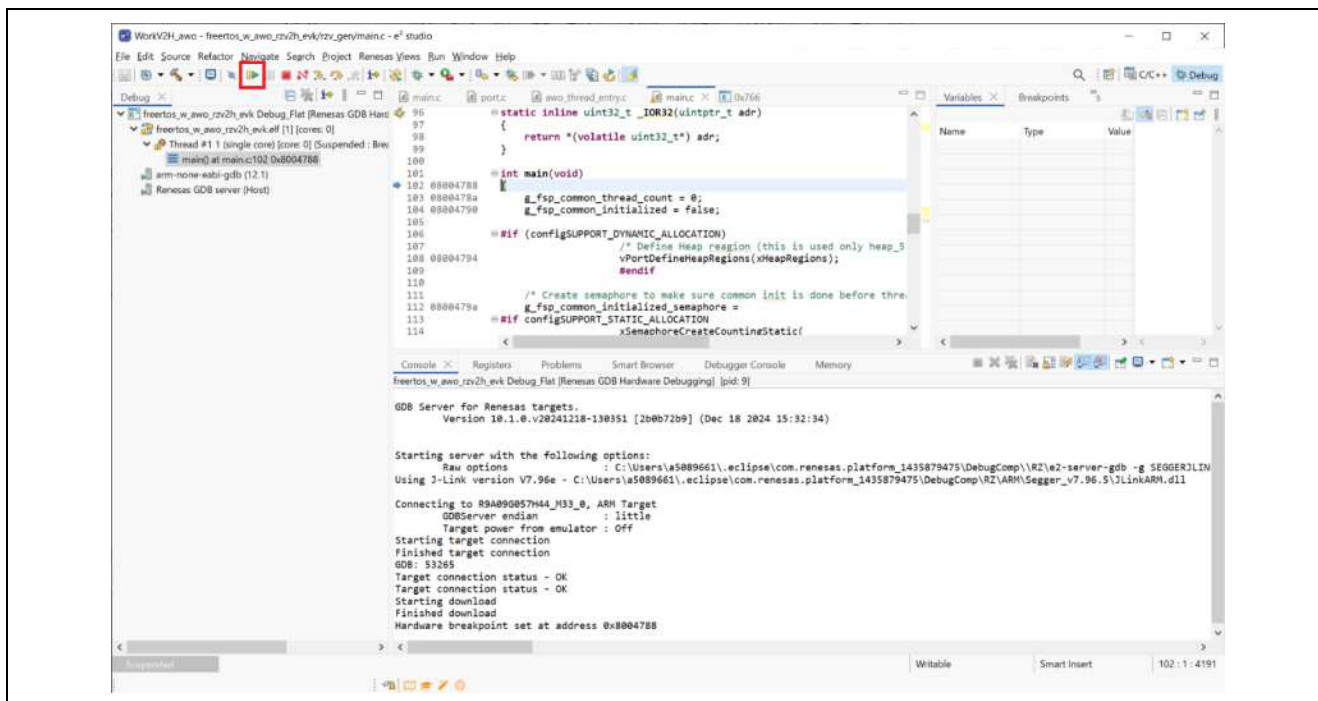


Figure 3-10. How to start to AWO Example Program (2)

CM33 AWO example program now starts, loads CA55 build artifacts and kick CA55.

4. AWO Example Program Invocation

This chapter describes how AWO Example Program works.

1. Boot up Linux kernel.
2. Login as **root**.

```
smarc-rzg3e login: root
```

3. Load **AWO Notifier** which notifies CM33 that CA55 becomes ready to enter AWO.

```
root@smarc-rzg3e:~# insmod ./awo-notifier.ko
```

4. Issue shutdown command as shown below:

```
root@smarc-rzg3e:~# shutdown -h now
```

While CA55 is being shut down, AWO Notifier fires an external interrupt.

5. Once CM33 AWO example project detects the external interrupt, RZ/G3E is configured as AWO. Then, the following message is shown on your console:

```
CM33: AWO request accept.  
Hit any key to go to ALLON mode.
```

6. When hitting any key on your development PC, CM33 AWO example project configures RZ/G3E as ALLON, load BL2 of TrustedFirmware-A to internal SRAM and kick CA55 for restart.

```
CM33: Set GreenPAK to ALLON
```

5. Function Reference of AWO Example Project

5.1.1 awo_thread_entry

```
void awo_thread_entry (void *pvParameters)
```

- **Parameters**

- pvParameters
Pointer to the parameter passed to AWO task.

- **Returns**

None

- **Description**

This function is the entry function of AWO thread.

Here is the overview of processing flow:

1. Wait for notification of shutdown from Arm® Cortex®-A55 (hereinafter referred to as CA55) Linux.
2. Configure RZ/G3E and PMIC as AWO.
3. Wait until key input to console is issued.
4. Configure RZ/G3E and PMIC as ALLON.
5. Return to 1.

5.1.2 awo_req_isr

```
void awo_req_isr (void)
```

- **Parameters**

- None

- **Returns**

None

- **Description**

This function is an interrupt handler that receives inter-core interrupts from CA55.

5.1.3 transition_to_awo

```
static void transition_to_awo(void)
```

- **Parameters**

None

- **Returns**

None

- **Description**

Transitioning the Power Mode of the RZ/G3E from ALL_ON to AWO.

5.1.4 transition_to_all_on

```
static void transition_to_all_on(void)
```

- **Parameters**

None

- **Returns**

None

- **Description**

Transitioning the Power Mode of the RZ/G3E from AWO to ALL_ON.

5.1.5 pmic_sleep_to_active

```
fsp_err_t pmic_sleep_to_active(void)
```

- **Parameters**

None

- **Returns**

Returns a FSP_SUCCESS upon successful completion.

If an error occurs in I2C communication, the error code returned by the I2C driver is returned.

- **Description**

Configure Power/Reset control IC GreenPAK SLG7RN47054 mounted on RZ/G3E SMARC EVK specific to AWO mode.

5.1.6 cluster_warm_reset_ca55

```
void cluster_warm_reset_ca55(void)
```

- **Parameters**

None

- **Returns**

None

- **Description**

Carry out Normal Reset Procedure of CA55.

5.1.7 release_cluster_warm_reset_ca55

```
void release_cluster_warm_reset_ca55(void)
```

- **Parameters**

- None

- **Returns**

None

- **Description**

Carry out Normal Reset Release and Core 0 Startup Procedure of CA55.

Revision History

Rev.	Date	Description	
		Page	Summary
1.00	Jul 22, 2025	-	First edition.

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2. Processing at power-on

The state of the product is undefined at the time when power is supplied. The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the time when power is supplied. In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the time when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the time when power is supplied until the power reaches the level at which resetting is specified.

3. Input of signal during power-off state

Do not input signals or an I/O pull-up power supply while the device is powered off. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Follow the guideline for input signal during power-off state as described in your product documentation.

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(Rev.5.0-1 October 2020)

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